

EPITAXIAL AVALANCHE DIODES

Glass passivated rectifier diodes in hermetically sealed axial-leaded ID* envelopes. They feature low forward voltage drop, very fast recovery, very low stored charge, non-snap-off switching characteristics and are capable of absorbing reverse transient energy (e.g. during flashover in a picture tube). These properties make the diodes very suitable for use in switched-mode power supplies and in general high-frequency circuits, where low conduction and switching losses are essential.

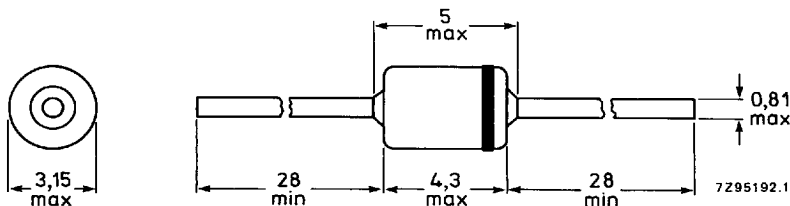
QUICK REFERENCE DATA

		BDY74A	B	C	D	E	F	G	
Repetitive peak reverse voltage	V_{RRM}	max. 50	100	150	200	250	300	400	V
Continuous reverse voltage	V_R	max. 50	100	150	200	250	300	400	V
Average forward current	$I_F(AV)$	max. 2,4	2,4	2,4	2,4	2,15	2,15	2,15	A
Non-repetitive peak forward current	I_{FSM}	max. 50	50	50	50	50	50	50	A
Non-repetitive peak reverse energy	E_{RSM}	max. 40	40	40	40	40	40	40	mJ
Reverse recovery time	t_{rr}	< 25	25	25	25	50	50	50	ns

MECHANICAL DATA

Dimensions in mm.

Fig. 1 SOD-84.



The marking band indicates the cathode.

* Implosion diode.

BYD74 SERIES

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

		BYD74A	B	C	D	E	F	G	
Repetitive peak reverse voltage	V_{RRM}	max. 50	100	150	200	250	300	400 V	
Continuous reverse voltage	V_R	max. 50	100	150	200	250	300	400 V	
Average forward current square wave; $\delta = 0,5$ $T_{tp} = 55\text{ }^\circ\text{C}$; lead length = 10 mm $T_{amb} = 60\text{ }^\circ\text{C}$; Fig. 2		$I_{F(AV)}$	max. 2,4	2,4	2,4	2,4	2,15	2,15	2,15 A
Repetitive peak forward current $T_{tp} = 55\text{ }^\circ\text{C}$; see Figs 11 and 13 $T_{amb} = 60\text{ }^\circ\text{C}$; see Figs 12 and 14		$I_{F(AV)}$	max. 1,35	1,35	1,35	1,35	1,2	1,2	1,2 A
Non-repetitive peak forward current ($t = 10\text{ ms}$; half sine-wave) $T_j = T_j\text{ max}$ prior to surge; with reapplied V_{RRM}		I_{FRM}	max. 21	21	21	21	21	21	21 A
		I_{FRM}	max. 13	13	13	13	12	12	12 A
Non-repetitive peak reverse avalanche energy; with inductive load switched-off: $I_R = 820\text{ mA}$ at $T_j = 25\text{ }^\circ\text{C}$ prior to surge $I_R = 580\text{ mA}$ at $T_j = T_j\text{ max}$ prior to surge		I_{FSM}	max.			50			A
		E_{RSM}	max.		40				mJ
		E_{RSM}	max.		20				mJ
Storage temperature	T_{stg}			-65 to + 175				$^\circ\text{C}$	
Junction temperature	T_j	max.			175			$^\circ\text{C}$	

THERMAL RESISTANCE

Influence of mounting method

1. Thermal resistance from junction to tie-point at a lead length of 10 mm
2. Thermal resistance from junction to ambient when mounted on a 1,5 mm thick epoxy-glass printed-circuit board; Cu-thickness $\geq 40\text{ }\mu\text{m}$ (see "Thermal model")

$R_{th\ j-tp} =$	50	K/W
$R_{th\ j-a} =$	105	K/W

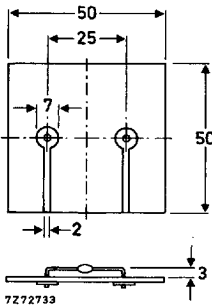
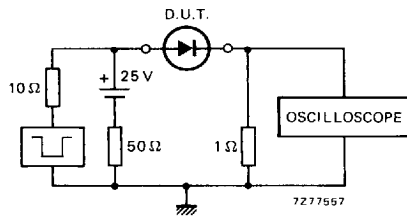


Fig. 2 Mounted on a printed-circuit board.

CHARACTERISTICS

$T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

	BYD74A	B	C	D	E	F	G	
Reverse avalanche breakdown voltage $I_R = 0,1\text{ mA}$	$V_{(BR)R} >$	55	110	165	220	275	330	440 V
Forward voltage* $I_F = 2\text{ A}; T_j = T_{j\text{ max}}$ $I_F = 2\text{ A}$	$V_F <$ $V_F <$	0,72 0,94	0,72 0,94	0,72 0,94	0,72 0,94	0,82 1,05	0,82 1,05	0,82 V 1,05 V
Reverse current $V_R = V_{RRM\text{ max}}; T_j = 25\text{ }^\circ\text{C}$ $V_R = V_{RRM\text{ max}}; T_j = 165\text{ }^\circ\text{C}$	$I_R <$ $I_R <$	1 150	1 150	1 150	1 150	1 150	1 150	μA μA
Reverse recovery time when switched from $I_F = 0,5\text{ A}$ to $I_R = 1\text{ A}$; measured at $I_R = 0,25\text{ A}$. For definition see Figs 3 and 4	$t_{rr} <$	25	25	25	25	50	50	ns



Input impedance oscilloscope $1\text{ M}\Omega; 22\text{ pF}$. Rise time $\leq 7\text{ ns}$.
Source impedance $50\text{ }\Omega$. Rise time $\leq 15\text{ ns}$.

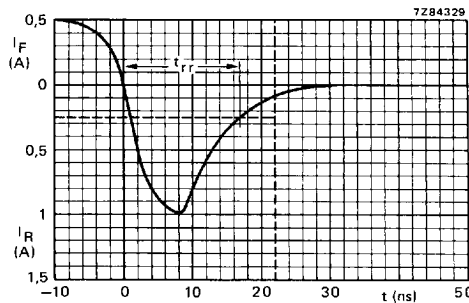


Fig. 4 Reverse recovery time characteristic.

* Measured under pulse conditions to avoid excessive dissipation.

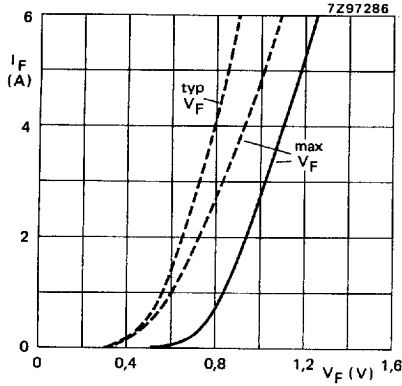


Fig. 5 BYD74A; B; C; D. Forward voltage;
— $T_j = 25\text{ }^\circ\text{C}$; - - - $T_j = T_j \text{ max}$.

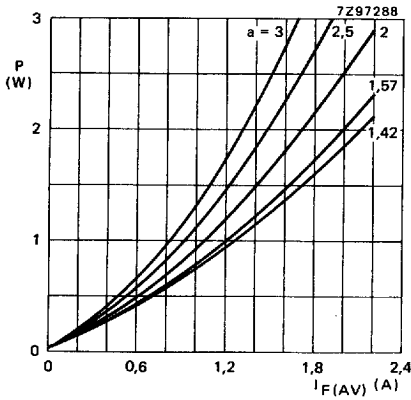


Fig. 6 BYD74A; B; C; D. Maximum values steady state power dissipation (forward plus leakage current) excluding switching losses as a function of the average forward current.

The graph is for switched-mode application.
 $a = I_F(\text{RMS})/I_F(\text{AV})$; $V_R = V_{RRM\text{max}}$, $\delta = 0,5$.

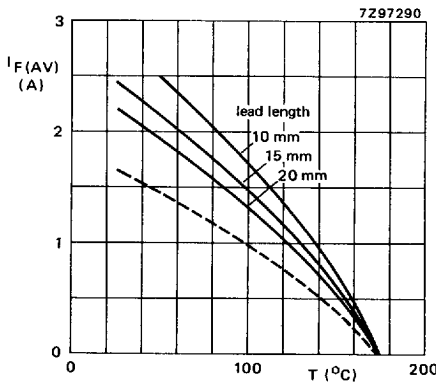


Fig. 7 BYD74A; B; C; D. Maximum average forward current as a function of temperature; the curves include losses due to reverse leakage.

The graph is for switched-mode application.

$V_R = V_{RRM\text{max}}$, $\delta = 0,5$; $a = 1,42$.

- - - = ambient temperature and device mounted as shown in Fig. 2

— = tie-point temperature

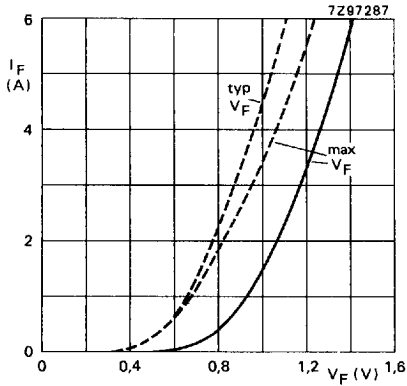


Fig. 8 **BYD74E; F; G.** Forward voltage;
— $T_j = 25\text{ }^\circ\text{C}$; - - - $T_j = T_j\text{ max.}$

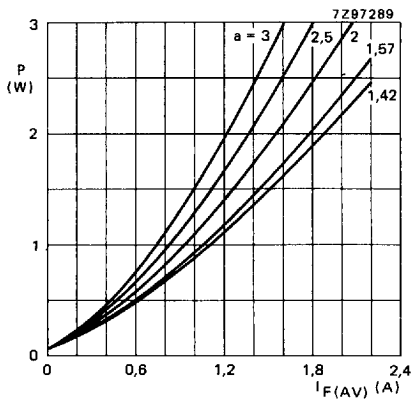


Fig. 9 **BYD74E; F; G.** Maximum values steady state power dissipation (forward plus leakage current) excluding switching losses as a function of the average forward current.

The graph is for switched-mode application.
 $a = I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RRMmax}$, $\delta = 0,5$.

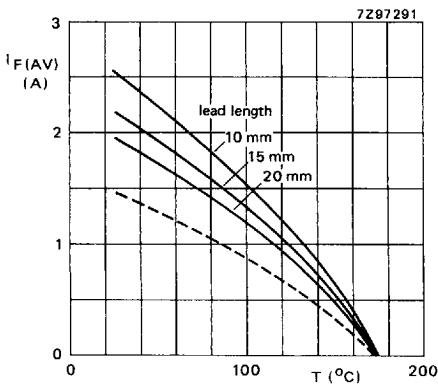


Fig. 10 **BYD74E; F; G.** Maximum average forward current as a function of temperature; the curves include losses due to reverse leakage.

The graph is for switched-mode application.

$V_R = V_{RRMmax}$, $\delta = 0,5$; $a = 1,42$.

- - - = ambient temperature and device mounted as shown in Fig. 2
— = tie-point temperature

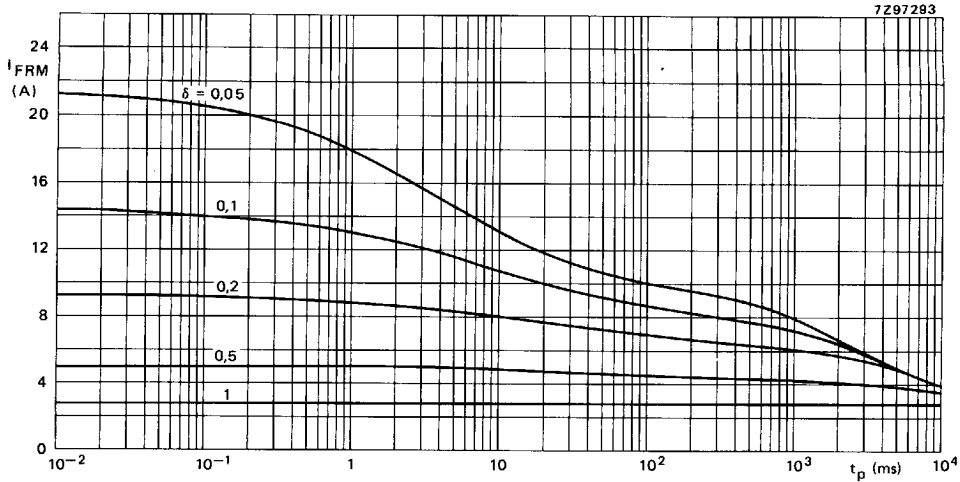


Fig. 11 BYD74A; B; C; D. Maximum repetitive peak forward current as a function of the pulse time (square pulse) and duty-factor δ at $T_{\text{tie-point}} = 55^\circ\text{C}$; $R_{\text{th j-tp}} = 50\text{ K/W}$; V_{RRM} during $1 - \delta$; the curves include derating for $T_{\text{j max}}$ at $V_{\text{RRM}} = 200\text{ V}$.

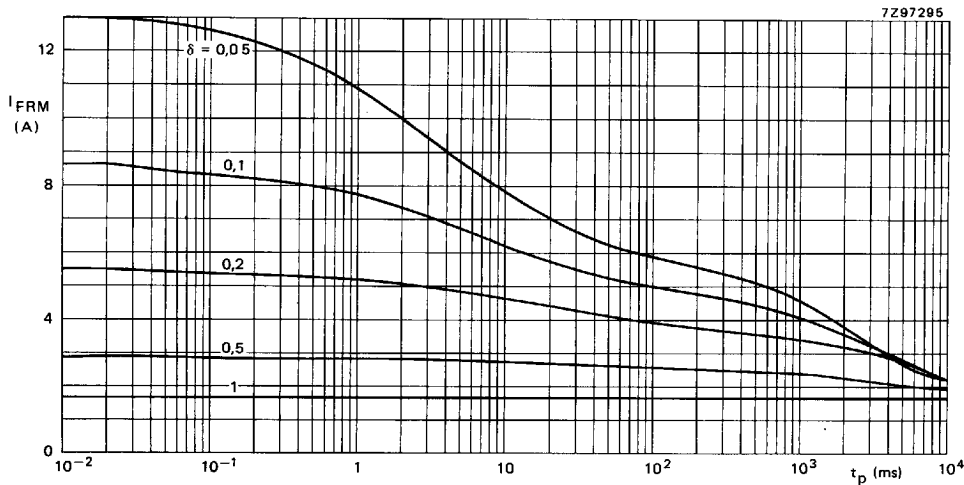


Fig. 12 BYD74A; B; C; D. Maximum repetitive peak forward current as a function of the pulse time (square pulse) and duty factor δ at $T_{\text{amb}} = 60^\circ\text{C}$; $R_{\text{th j-a}} = 105\text{ K/W}$; V_{RRM} during $1 - \delta$; the curves include derating for $T_{\text{j max}}$ at $V_{\text{RRM}} = 200\text{ V}$.

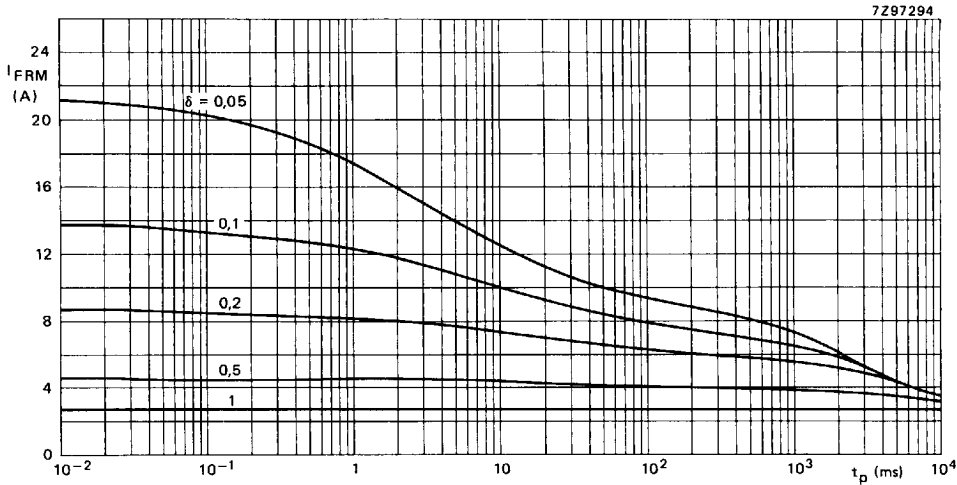


Fig. 13 BYD74E; F; G. Maximum repetitive peak forward current as a function of the pulse time (square pulse) and duty-factor δ at $T_{tie-point} = 55^\circ C$; $R_{th j-tp} = 50 K/W$; V_{RRM} during $1 - \delta$; the curves include derating for $T_{j max}$ at $V_{RRM} = 400 V$.

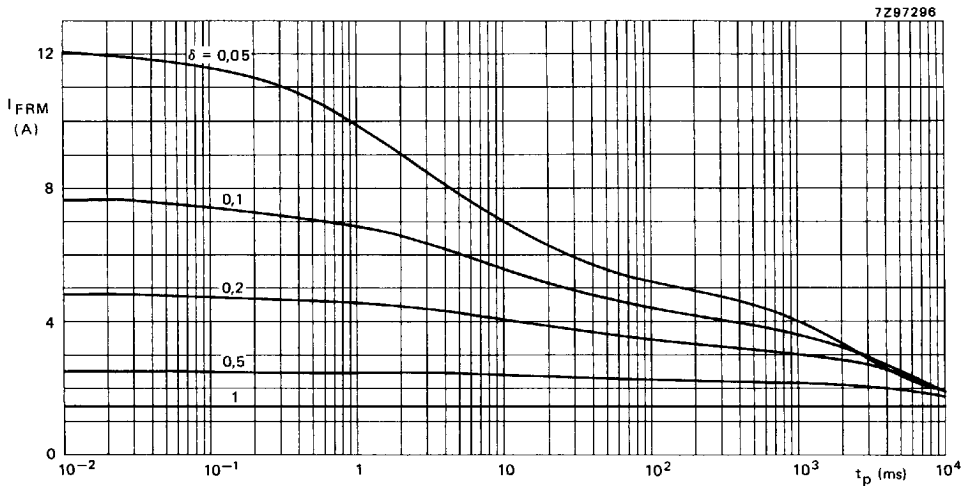


Fig. 14 BYD74E; F; G. Maximum repetitive peak forward current as a function of the pulse time (square pulse) and duty-factor δ at $T_{amb} = 60^\circ C$; $R_{th j-a} = 105 K/W$; V_{RRM} during $1 - \delta$; the curves include derating for $T_{j max}$ at $V_{RRM} = 400 V$.

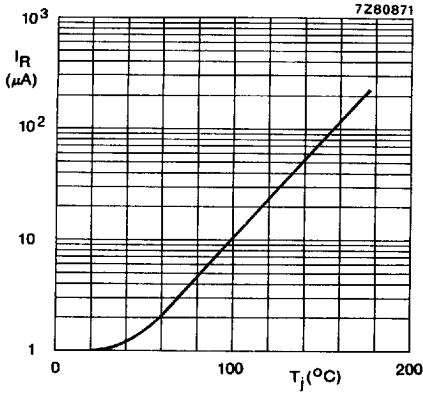


Fig. 15 Maximum values reverse current as a function of junction temperature; $V_R = V_{RRMmax}$.

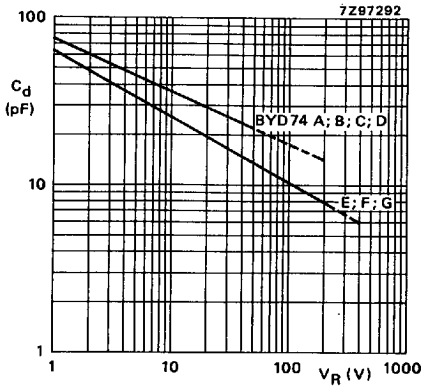


Fig. 16 Capacitance as a function of reverse voltage; $f = 1$ MHz; $T_j = 25$ $^{\circ}C$; typical values.